NSN 5962-01-058-6744

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-058-6744 **Body Length:** 0.840 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** 0.185 inches **Maximum Power Dissipation Rating:** 660.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Radar set type an/aps-125 **Features Provided:** Hermetically sealed and monolithic and positive outputs and w/enable and w/disable and programmable and programmed and w/open collector **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Case Outline Source And Designator:** D-2 mil-m-38510 **Terminal Surface Treatment:** Solder **Voltage Rating And Type Per Characteristic:** 5.5 volts power source **Memory Device Type:** Rom **Memory Capacity:** Unknown **Special Features:** Bit pattern table no. 5

Test Data Document:

27963-57991100 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

24 printed circuit

Shelf Life:

N/a

NSN 5962-01-058-6744

Memory Microcircuit - Page 2 of 2



			ure:	

--

Demilitarization:

Yes - demil/mli

Fiig:

A458a0